

## Specification Sheet

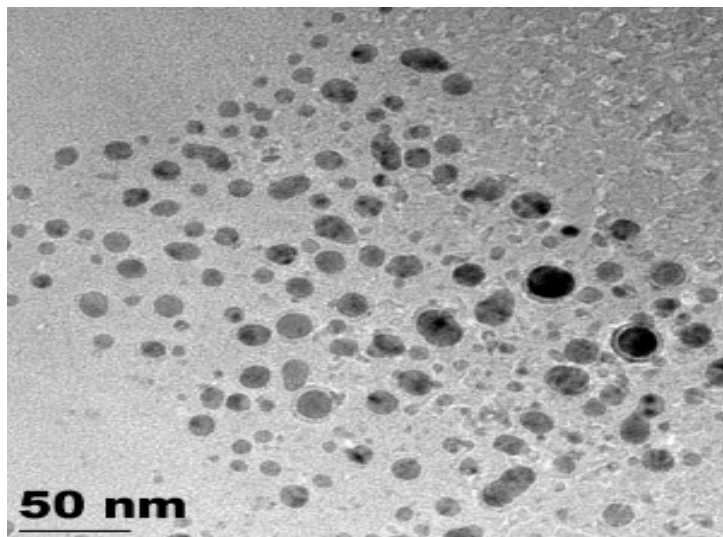
InGaAs, Purity: 99.9%, APS: <100 nm

Stock No: NS6130-12-000344, CAS: 106097-59-0

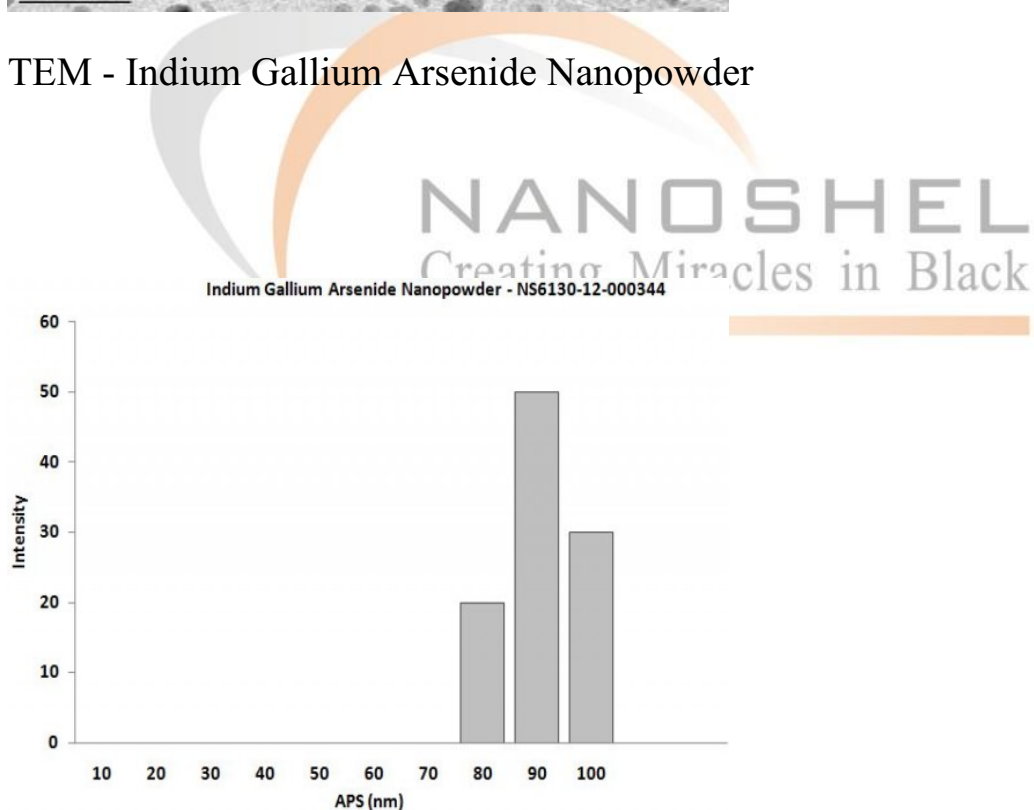
<b>Product</b>	:	<b>Indium Gallium Arsenide Nanopowder</b>
Stock No.	:	NS6130-12-000344
CAS	:	106097-59-0
Purity	:	99.9%
APS	:	< 100 nm
Molecular Formula	:	InGaAs
Molecular Weight	:	259.46 g/mol
Form	:	Crystalline Powder
color	:	White
Density	:	5.68 g/cm <sup>3</sup>
Melting Point	:	844 °C
Conclusion	:	The specifications Confirm with enterprise standard
<b>Main Inspect Verifier</b>	:	<b>Manager QC</b>

**Note:** Product Specification are subject to amendment and may change over time

## Characterization of InGaAs, Purity: 99.9%, APS: <100 nm



## TEM - Indium Gallium Arsenide Nanopowder



## Particles Size Analysis - Indium Gallium Arsenide Nanopowder